

**ADVANCED
POWER
TECHNOLOGY** T-39-15

APT4020AN 400V 22.5A 0.20 Ω
 APT3520AN 350V 22.5A 0.20 Ω
 APT4025AN 400V 20.0A 0.25 Ω
 APT3525AN 350V 20.0A 0.25 Ω

POWER MOS IV™

N - CHANNEL ENHANCEMENT MODE HIGH VOLTAGE POWER MOSFETS

MAXIMUM RATINGS

All Ratings: $T_C = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter	APT				UNIT
		3520AN	4020AN	3525AN	4025AN	
V _{DSS}	Drain-Source Voltage	350	400	350	400	Volts
I _D	Continuous Drain Current	22.5		20		Amps
I _{DM}	Pulsed Drain Current ¹	90		80		Amps
V _{GS}	Gate-Source Voltage	±30				Volts
P _D	Total Power Dissipation @ T _C = 25°C, Derate Above 25°C	230				Watts
T _J , T _{STG}	Operating and Storage Junction Temperature Range	- 55 to 150				°C

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions / Part Number		MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage ($V_{GS} = 0V, I_D = 250 \mu A$)	APT4020AN / APT4025AN	400			Volts
		APT3520AN / APT3525AN	350			Volts
I_{DSS}	Zero Gate Voltage Drain Current ($V_{DS} = V_{DSS}, V_{GS} = 0V$) ($V_{DS} = 0.8 V_{DSS}, V_{GS} = 0V, T_C = 125^\circ\text{C}$)				250	μA
					1000	
I_{GSS}	Gate-Source Leakage Current ($V_{GS} = \pm 30V, V_{DS} = 0V$)				± 100	nA
$I_{D(ON)}$	On State Drain Current ² ($V_{DS} > I_{D(ON)} \times R_{DS(ON)}$ Max, $V_{GS} = 10V$)	APT4020AN / APT3520AN	22.5			Amps
		APT4025AN / APT3525AN	20			Amps
$V_{GS(TH)}$	Gate Threshold Voltage ($V_{DS} = V_{GS}, I_D = 1mA$)		2		4	Volts
$R_{DS(ON)}$	Static Drain-Source On-State Resistance ² ($V_{GS} = 10V, I_D = 0.5 I_{D(ON)}$ [Cont.])	APT4020AN / APT3520AN			0.20	Ohms
		APT4025AN / APT3525AN			0.25	Ohms

THERMAL CHARACTERISTICS

Symbol	Characteristic	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to Case			0.53	$^\circ\text{C/W}$
$R_{\theta JA}$	Junction to Ambient			30	$^\circ\text{C/W}$
T_L	Max. Lead Temp. for Soldering Conditions: 0.063" from Case for 10 Sec.			300	$^\circ\text{C}$

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DYNAMIC CHARACTERISTICS

APT4020/3520/4025/3525AN

Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
C_{iss}	Input Capacitance	$V_{GS} = 0V$ $V_{DS} = 25V$ $f = 1 \text{ MHz}$		2380	2950	pF
C_{oss}	Output Capacitance			563	750	pF
C_{rss}	Reverse Transfer Capacitance			207	310	pF
Q_g	Total Gate Charge ³	$V_{GS} = 10V, I_D = I_D [\text{Cont.}]$ $V_{DD} = 0.5 V_{DSS}$		94	130	nC
Q_{gs}	Gate-Source Charge			11	16	nC
Q_{gd}	Gate-Drain ("Miller") Charge			47	70	nC
$t_{d(on)}$	Turn-on Delay Time	$V_{DD} = 0.5 V_{DSS}$ $I_D = I_D [\text{Cont.}], V_{GS} = 15V$ $R_G = 1.8\Omega$		14	28	ns
t_r	Rise Time			29	57	ns
$t_{d(off)}$	Turn-off Delay Time			60	90	ns
t_f	Fall Time			40	80	ns

SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS

T-39-15

Symbol	Characteristic / Test Conditions / Part Number	MIN	TYP	MAX	UNIT
I_S	Continuous Source Current (Body Diode)	APT4020AN / APT3520AN		22.5	Amps
		APT4025AN / APT3525AN		20	Amps
I_{SM}	Pulsed Source Current ¹ (Body Diode)	APT4020AN / APT3520AN		90	Amps
		APT4025AN / APT3525AN		80	Amps
V_{SD}	Diode Forward Voltage ² ($V_{GS} = 0V, I_S = -I_D [\text{Cont.}]$)			1.3	Volts
t_{rr}	Reverse Recovery Time ($I_S = -I_D [\text{Cont.}], di_S/dt = 100A/\mu s$)	180	360	720	ns
Q_{rr}	Reverse Recovery Charge	3	6	12	μC

SAFE OPERATING AREA CHARACTERISTICS

Symbol	Characteristic	Test Conditions / Part Number	MIN	TYP	MAX	UNIT
SOA1	Safe Operating Area	$V_{DS} = 0.4 V_{DSS}, I_{DS} = P_D / 0.4 V_{DSS}, t = 1 \text{ Sec.}$	230			Watts
SOA2	Safe Operating Area	$I_{DS} = I_D [\text{Cont.}], V_{DS} = P_D / I_D [\text{Cont.}], t = 1 \text{ Sec.}$	230			Watts
I_{LM}	Inductive Current Clamped	APT4020AN / APT3520AN	90			Amps
		APT4025AN / APT3525AN	80			Amps

1.) Repetitive Rating: Pulse width limited by maximum junction temperature. See Transient Thermal Impedance Curve. (Fig.1)

2.) Pulse Test: Pulse width < 380 μs
Duty Cycle < 2%
3.) See MIL-STD-750 Method 3471

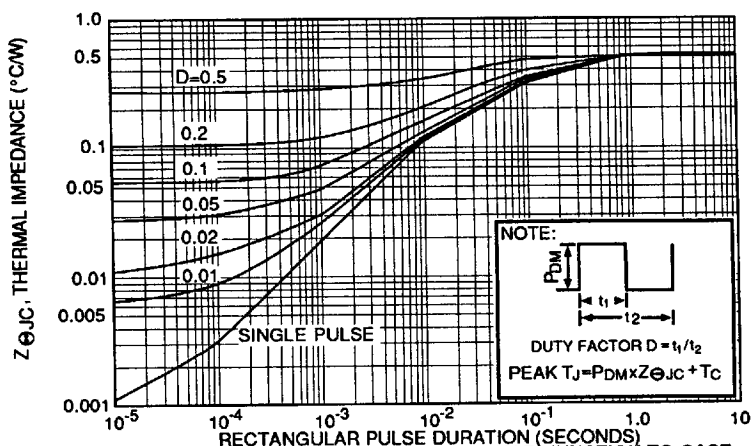
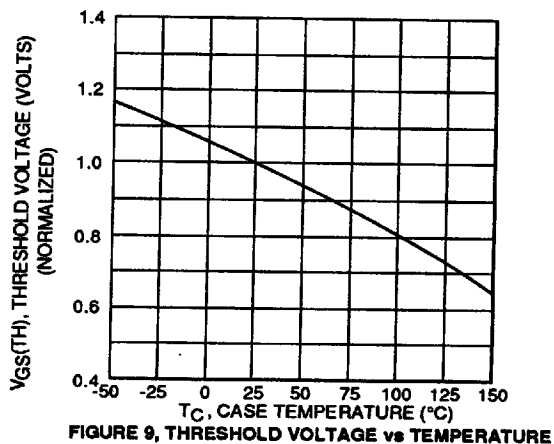
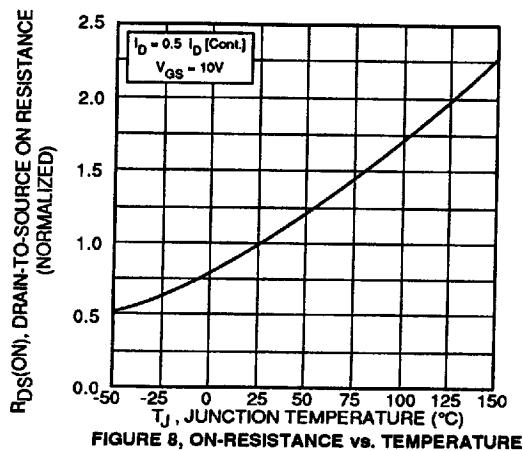
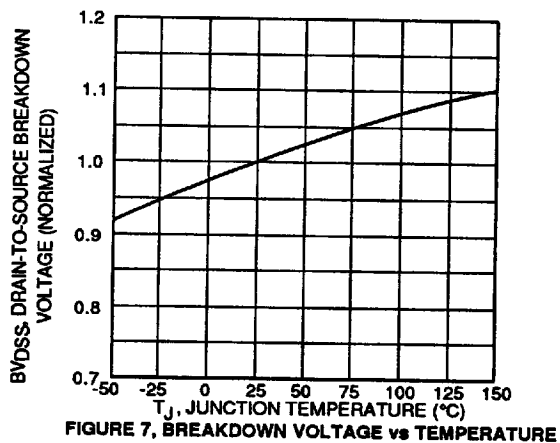
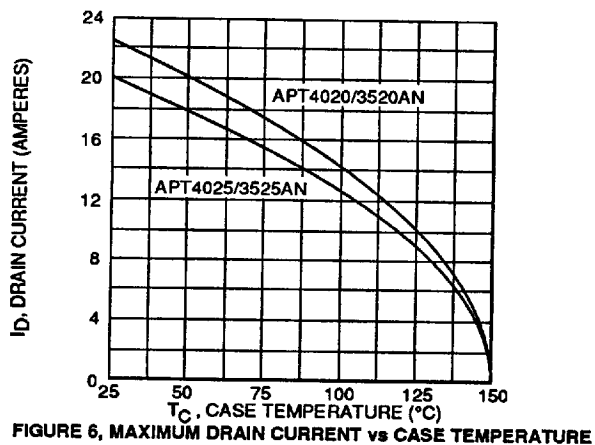
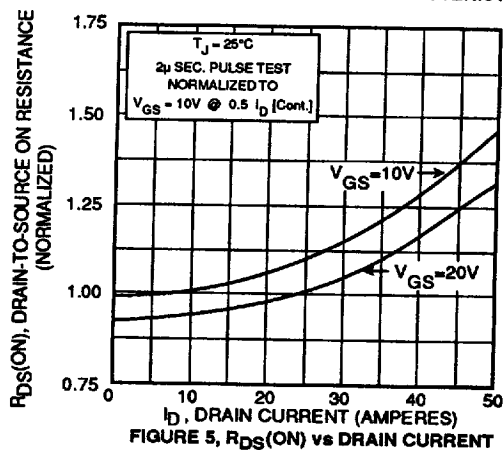
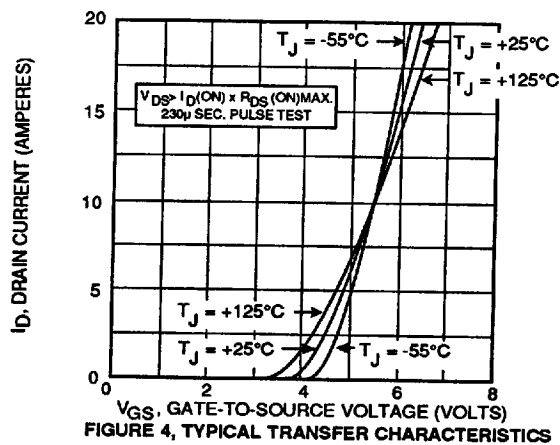
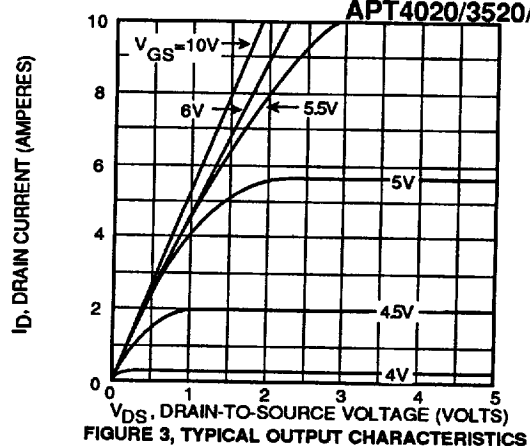
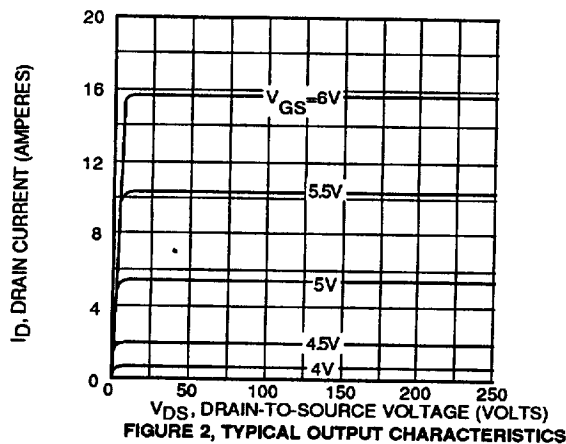
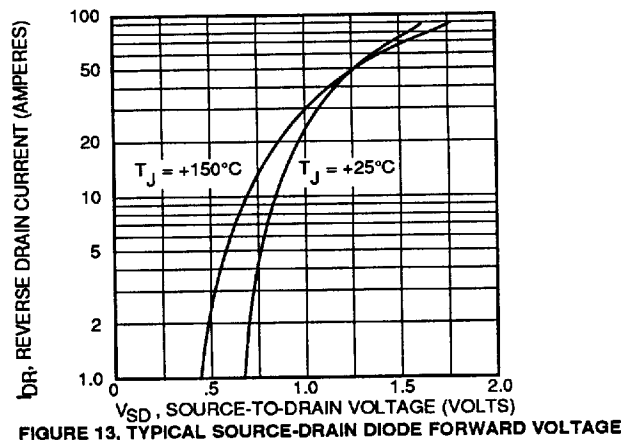
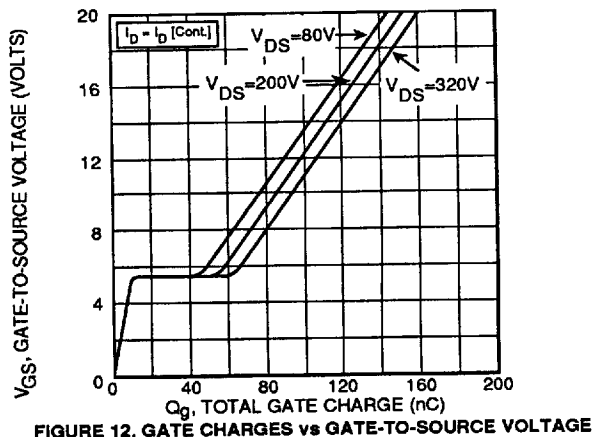
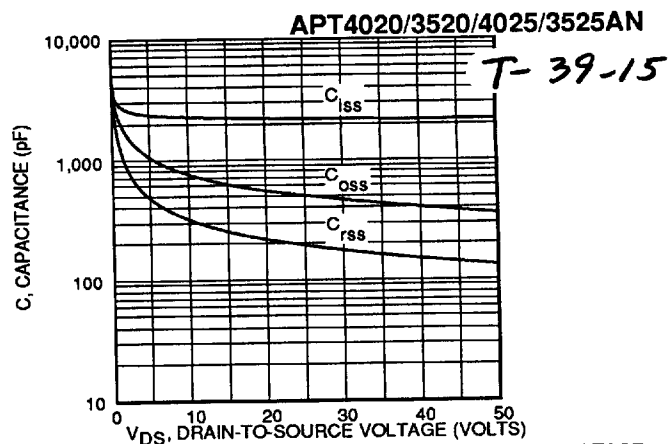
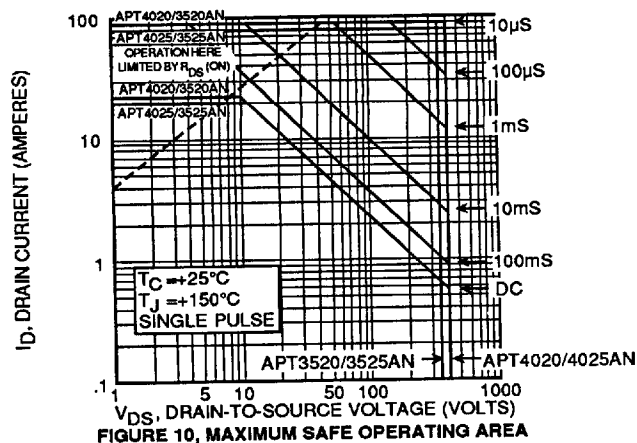
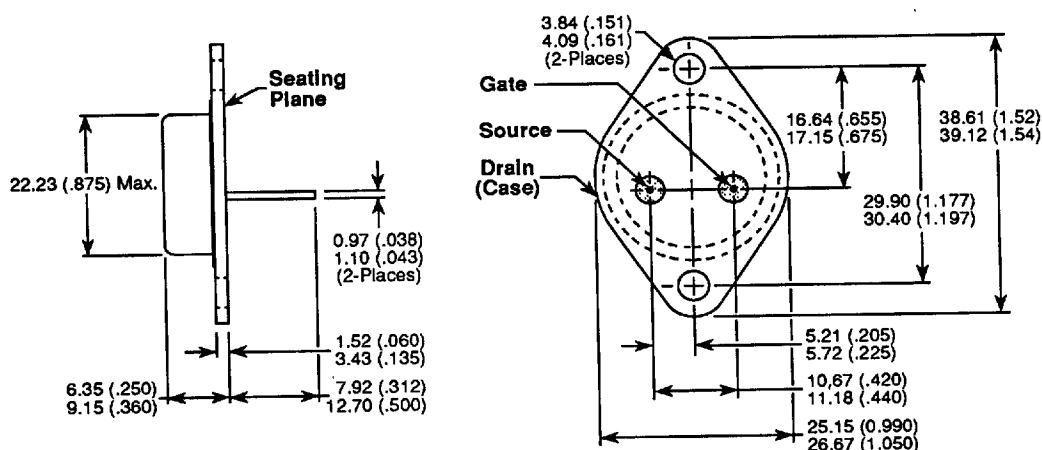


FIGURE 1, MAXIMUM EFFECTIVE TRANSIENT THERMAL IMPEDANCE, JUNCTION-TO-CASE vs PULSE DURATION





TO-3 Package Outline (TO-204AA)



Dimensions in Millimeters and (Inches)